MOS Memory Interface Circuits

DS1642/DS3642, DS1672/DS3672 Dual Bootstrapped TTL to MOS Clock Drivers

General Description

The DS1672 is a dual bipolar-to-MOS clock driver designed to provide high output current and voltage capabilities necessary for driving high capacitance (up to 500 pF) MOS memory systems. The circuit needs only one power supply, (12V typical). This feature greatly reduces high stand-by power levels and at the same time simplifies system deisgn.

The circuit also features output bootstrapping, eliminating the need for an additional supply to provide a higher voltage to the output stage. The function is accomplished by connecting a small value capacitor (typically 200 pF) from the output to the bootstrap pin on each driver.

The circuit has Schottky-clamped transistor logic for minimum propagation delay. Typical stand-by power (output low) is 48 mW per driver. A fail-safe condition is provided in the circuit, so if the input is opened the output assumes the logic "0" state.

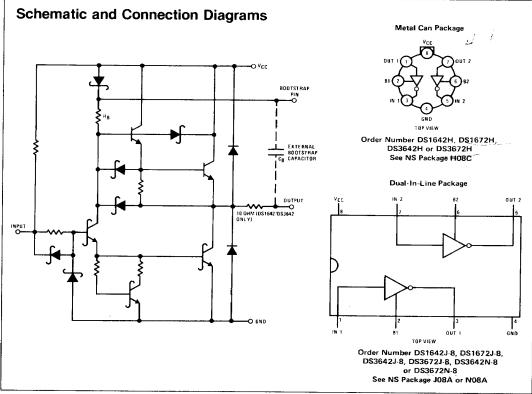
The DS1642/DS3642 has a 10 Ω resistor in series with each output to dampen transients caused by the fast-switching output. The DS1672/DS3672 has a direct low impedance output for use with or without an external resistor.

Features

- High output voltage capability
- 13.2V
- TTL/DTL compatible inputs
- High speed operation
- Bootstrapping eliminates extra supplies—reduces power
- Low stand-by power

48 mW/driver

 \blacksquare Built in 10 Ω damping resistor (DS1642/DS3642)



Absolute Maximum Rating	Operating Conditions				
Supply Voltage	15V		MIN	MAX	UNITS
Bootstrap-V _{CC} Differential	15V	Supply Voltage (VCC)			
Bootstrap Pin Voltage	30V	DS1642, DS1672	10.8	13.2	v
Input Voltage	5.5V	DS3642, DS3672	11.4	12.6	V
Input Current	10 mA	D33042, D33672	11.4	12.0	v
Output Voltage	-1.0V to +15V	Bootstrap-V _{CC} Differential			
Storage Temperature Range	-65° C	Voltage (VB-VCC)			
Power Dissipation*		DS1642, DS1672	10.8	13.2	. V
Cavity Package	1160 mW	DS3642, DS3672	11.4	12.6	V
Molded Package	890 mW	Temperature (T _A)			
Metal Can	525 mW	DS1642, DS1672	∕ 55	+125	°C
Lead Temperature (Soldering, 10 seconds)	300° C	DS3642, DS3672	/ o	+70	°C

DC Electrical Characteristics (Notes 2 and 3)

DS1642, DS1672

200° C/W above 70° C.

 $V_{\mbox{CC}}$ = 12V ±10%, –55°C \leq $T_{\mbox{A}} \leq$ +125°C, unless otherwise noted.

DS3642, DS3672

 $V_{CC} = 12V \pm 5\%$, $0^{\circ}C \le T_{A} \le +70^{\circ}C$, unless otherwise noted.

	PARAMETER	CONDITIO	ONS	MIN	TYP	MAX	UNITS
I ₁ T	Logical "1" Input Current			200	0		μΑ
VIL	Logical "0" Input Voltage					0.8	V
I _[H] Logical "1" Input Current (Note 5)	VIN = 2.4V			0.9	1.5	mA	
	(Note 5)	V _{IN} = 5.5V			4	5.5	mA
HL	Logical "0" Input Current	V _{IN} = 0V			-240	-400	μА
v_{CD}	Input Clamp Voltage	I _{IN} = -5 mA			-0.9	-1.5	V
۷он	Logical "1" Output Voltage	V _B ≥ V _{CC} + 2V, I _{OUT} = -400 μA			V _{CC} -0.5	V _{CC} -0.8	V
VOL	Logical "0" Output Voltage	IOUT = 5 mA, Bootstrap Pin (Vg) Open, (Note 6)			0.3	0.5	V
RB	Bootstrap Resistor				3.0		kΩ
ICC(1) Supply Current	V _{IN} ≈ 0V, (Both Drivers "OFF"	, Bootstrap Pin (VB) Open		0.5	2.0	mA	
	Outputs Open	$V_B = V_{CC} + 7V$		-4.2	-6.0	mA	
¹ B(1)	Bootstrap Current	(Both Drivers), V _{IN} = 0V, V _B = V _{CC} + 7V			4.2	6.0	mA
CCIO	Supply Current	V _{IN} = 2.4V, Bootstrap Pin (V _B) Open	(Both Drivers "ON") Outputs Open		8.0	12	mA

Switching Characteristics (Note 4) (V_{CC} = 12V, T_A = 25°C) (Figures 1 and 2)

	PARAMETER	CON	DITIONS	MIN	TYP	MAX	UNITS
ts+_	t_{S+-} Storage Delay Negative Edge $R_{D} = 10 \Omega$	B= ::10 ()	CL = 50 pF		8	12	ns
		HD = 10.75	C _L = 500 pF		13	18	ns
ts-+	Storage Delay Positive Edge	R _D = 10 52	CL = 50 pF		8	12	ns
			C _L = 500 pF		13	18	ns
tF Fal	Fall Time RD = 10 (2	D 10 ()	CL = 50 pF		6	9	ns
		HD = 10.73	C _L = 500 pF		15	22	ns
t _R	Rise Time	0 10 ()	CL = 50 pF		6	9	ns
		HD = 10.75	C _L = 500 pF		15	22	ns

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. Except for "Operating Temperature Range" they are not meant to imply that the devices should be operated at these limits. The table of "Electrical Characteristics" provides conditions for actual device operation.

Note 2: Unless otherwise specified min/max limits apply across the -55° C to $+125^{\circ}$ C temperature range for the DS1642, DS1672 and across the 0° C to $+70^{\circ}$ C range for the DS3642, DS3672. All typicals are given for V_{CC} = 12V and T_{A} = 25 $^{\circ}$ C.

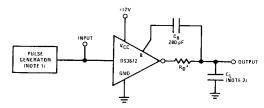
Note 3: All currents into device pins shown as positive, out of device pins as negative, all voltages referenced to ground unless otherwise noted. All values shown as max or min on absolute value basis.

Note 4: When measuring output drive current and switching response for the DS1672 and DS3672, a 10 Ω resistor should be placed in series with each output. This resistor is internal to the DS1642/DS3642 and need not be added.

Note 5: The value of I_{1H} and I_{1L} given is intended to be a measure of input impedance and does not reflect the input threshold.

Note 6: $V_{\mbox{OL}}$ also applies to the fail-safe condition when the input is open.

AC Test Circuit



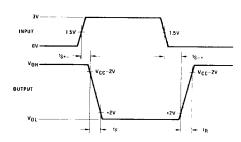
*Internal on DS1642/DS3642

Note 1: The pulse generator has the following characteristics: PRR = 1 MHz, 50% Duty Cycle, Z_{OUT} = 50Ω , t_{R} = $t_{F} \leq$ 10 ns. Note 2: C_{L} includes probe and jig capacitance.

Note 3: The high current transient (as high as 0.5A) through the resistance of the external interconnecting ground lead during the output transition from the high state to the low state can appear as negative feedback to the input. If the external interconnecting load from the driving circuit to ground is electrically long, or has significant do resistance, it can subtract from the switching response.

FIGURE 1

Switching Time Waveforms

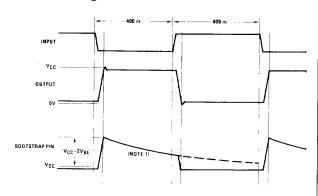


Note 1: The pulse generator has the following characteristics: PRR = 1 MHz, $t_R \leq$ 10 ns, $t_F \leq$ 10 ns, Z_{OUT} = 50Ω .

Note 2: CL includes probe and jig capacitance.

FIGURE 2

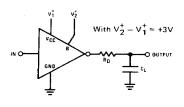
Node Voltage Waveforms



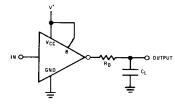
Note 1: The fall time has an exponential decay with the following time constant: $t_B = C_B R_B$. The typical value for R_B can be found in the table of electrical characteristics.

Typical Applications

DS3672 Operating with Extra Supply to Enhance Output Voltage Level



DS3672 in Non-Bootstrap Application with Single Supply—When Output High Level is Non-Critical.



DS3672 Bootstrap Mode of Application with Capacitively Coupled Input and Negative Supply

